



SBR1U40LP

### 1.0A SBR<sup>®</sup> SUPER BARRIER RECTIFIER

#### **Features**

- Ultra Low Forward Voltage Drop
- Excellent High Temperature Stability
- Patented Super Barrier Rectifier Technology
- · Soft, Fast Switching Capability
- 150°C Operating Junction Temperature
- Lead Free By Design, RoHS Compliant (Note 1)
- Halogen and Antimony Free "Green" Device (Notes 2 & 3)

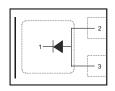
### **Mechanical Data**

- Case: X1-DFN1411-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish NiPdAu over Copper Lead Frame.
   Solderable per MIL-STD-202, Method 208
- Weight: 2.35mg (approximate)

#### X1-DFN1411-3







Top View

**Bottom View** 

Top View Internal Schematic

### Ordering Information (Note 4)

Part Number	Case	Packaging
SBR1U40LP-7	X1-DFN1411-3	3000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. No purposely added lead. Halogen and Antimony free.
- 2. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com.
- 4. For packaging details, go to our website at http://www.diodes.com

## **Marking Information**



<u>D</u>4 = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: U = 2007)
 M = Month (ex: 9 = September)

Date Code Key

Year	2007	20	08	2009	2010	20	11	2012	2013	20	14	2015
Code	<u>U</u>	\	/	W	X	,	Y	Z	Α	I	3	С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



## Maximum Ratings @TA = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage (Note 5) Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>RM</sub>	40	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	28	V
Average Rectified Output Current (See Figure 1)	l <sub>0</sub>	1.0	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	5	А
Non-Repetitive Peak Forward Surge Current 15s Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	2.6	А

### Thermal Characteristics

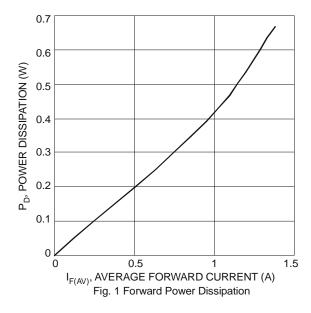
Characteristic	Symbol	Value	Unit	
Power Dissipation	$P_{D}$	400	mW	
Maximum Thermal Resistance Junction to Ambient (Note 6)	$R_{ heta JA}$	190	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C	

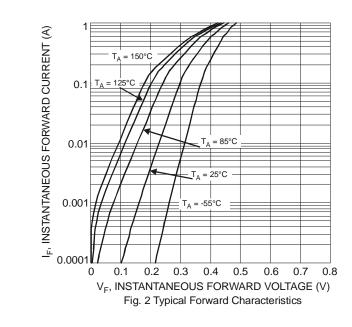
## Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Forward Voltage Drop	V <sub>F</sub>	-	0.39	0.42	V	$I_F = 0.5A, T_J = 25^{\circ}C$
		-	0.46	0.49		$I_F = 1.0A, T_J = 25^{\circ}C$
		-	0.34	0.37		$I_F = 0.5A, T_J = 125^{\circ}C$
		-	0.43	0.47		I <sub>F</sub> = 1.0A, T <sub>J</sub> = 125°C
akage Current (Note 7)	I <sub>R</sub>	-	-	50	μΑ	$V_R = 40V, T_J = 25^{\circ}C$
		-	-	100	mA	$V_R = 40V, T_J = 125^{\circ}C$

Notes:

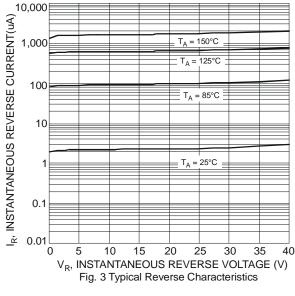
- 5.  $V_{RRM}$  characteristic is base on 1mA leakage current test condition 6. Device mounted on Polymide substrate 1" x 1", 2oz. Copper double sided PCB board.
- 7. Short duration pulse test used to minimize self-heating effect.

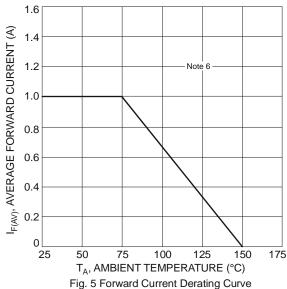




SBR is a registered trademark of Diodes Incorporated.







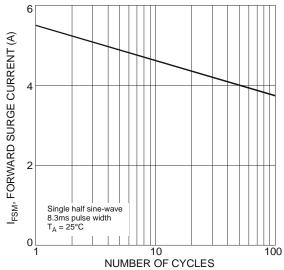


Fig. 7 Forward Surge Current vs. Number of Cycles

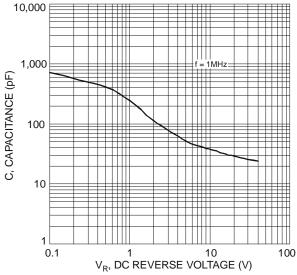
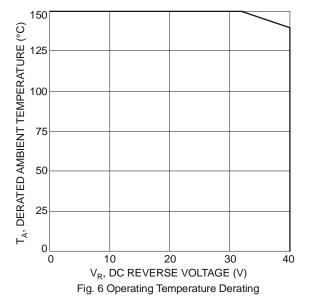
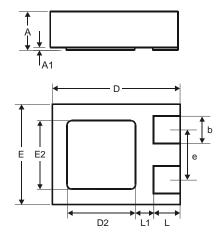


Fig. 4 Total Capacitance vs. Reverse Voltage



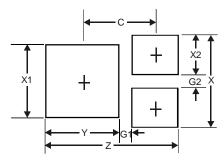


# **Package Outline Dimensions**



X1-DFN1411-3							
Dim	Min	Max	Тур				
Α	0.47	0.53	0.50				
A1	0	0.05	0.02				
b	0.25	0.35	0.30				
D	1.35	1.475	1.40				
D2	0.65	0.85	0.75				
Е	1.05	1.175	1.10				
E2	0.65	0.85	0.75				
е	_	_	0.55				
L	0.225	0.325	0.275				
L1			0.20				
All D	All Dimensions in mm						

# **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	1.38
G1	0.15
G2	0.15
Х	0.95
X1	0.75
X2	0.40
Υ	0.75
C	0.76



#### **IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

#### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2012, Diodes Incorporated

www.diodes.com

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Diodes Incorporated: SBR1U40LP-7